

## NCE P-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE01P13I uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications. It is ESD protested.

#### **General Features**

•  $V_{DS}$  =-100V, $I_{D}$  =-13A  $R_{DS(ON)}$  <200mΩ @  $V_{GS}$ =-10V (Typ:170mΩ)

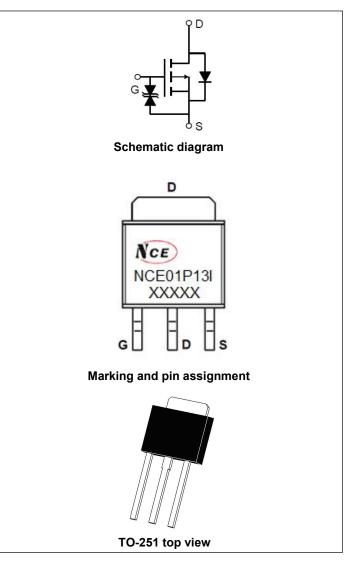
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density celldesign for ultra low on-resistance

## **Application**

- Power switch
- DC/DC converters

100% UIS TESTED!

100% ΔVds TESTED!



### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01P13I	NCE01P13I	TO-251	-	_	-

### Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-100	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	-13	Α
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	-9.2	Α
Pulsed Drain Current	I <sub>DM</sub>	-52	Α
Maximum Power Dissipation	P <sub>D</sub>	40	W
Derating factor		0.27	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	65	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	°C



### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case (Note 2)	R <sub>θJc</sub>	3.75	°C/W	
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## Electrical Characteristics (T<sub>C</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±10	μA
On Characteristics (Note 3)				,		
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-1	-1.9	-3	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-10A	-	170	200	mΩ
Forward Transconductance	<b>G</b> FS	V <sub>DS</sub> =-20V,I <sub>D</sub> =-10A	-	19	-	S
Dynamic Characteristics (Note4)				'		
Input Capacitance	C <sub>lss</sub>	)/ 50//\/ 0\/	-	1491	-	PF
Output Capacitance	Coss	$V_{DS}$ =-50V, $V_{GS}$ =0V,	-	47.5	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	41.8	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	12	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =-50V,I <sub>D</sub> =-10A	-	52	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =-10V,R <sub>GEN</sub> =9.1Ω	-	28	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	38	-	nS
Total Gate Charge	Qg	)/ 50\/L 40A	-	32.5	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-50V,I <sub>D</sub> =-10A,	-	5.2	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-10V	-	6.5	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-10A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	-13	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF =-10A	-	35	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	46	-	nC
Forward Turn-On Time	ton	Intrinsic turn-on time is negl	igible (turr	n-on is do	minated b	y LS+LD)

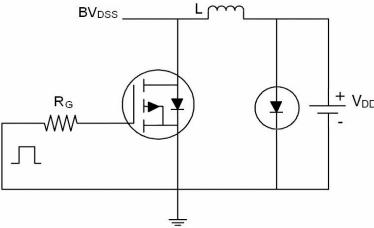
## Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 2\%$ .
- 4. Guaranteed by design, not subject to production
- **5.** E<sub>AS</sub> condition: Tj=25  $^{\circ}\text{C}$  ,V<sub>DD</sub>=-50V,V<sub>G</sub>=-10V,L=0.5mH,Rg=25 $\Omega$

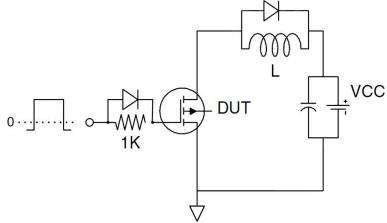


## **Test Circuit**

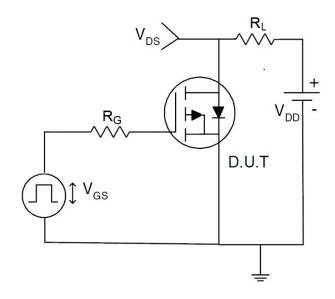
# 1) E<sub>AS</sub> Test Circuit



# 2) Gate Charge Test Circuit

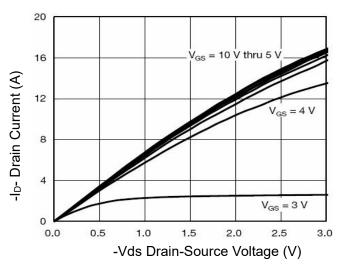


# 3) Switch Time Test Circuit

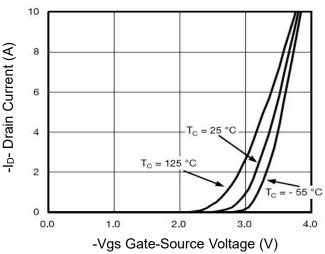




## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

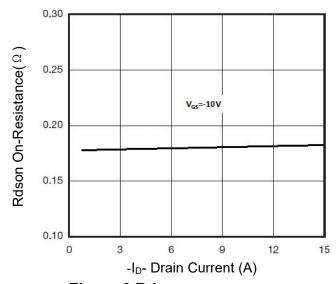
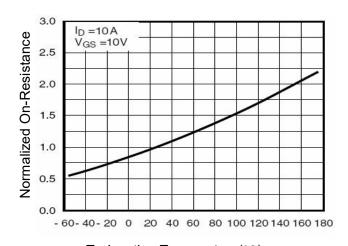


Figure 3 Rdson- Drain Current



T<sub>J</sub>-Junction Temperature(°C)

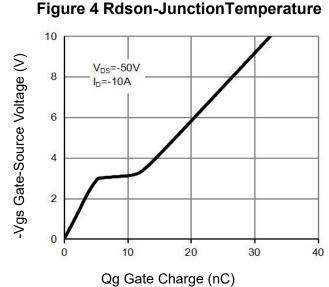


Figure 5 Gate Charge

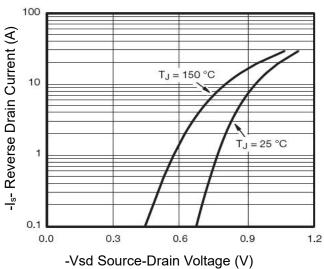


Figure 6 Source- Drain Diode Forward



C Capacitance (nF)

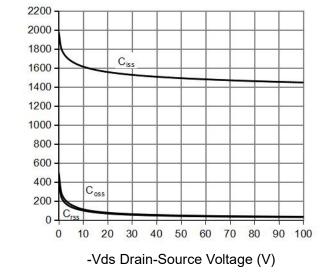
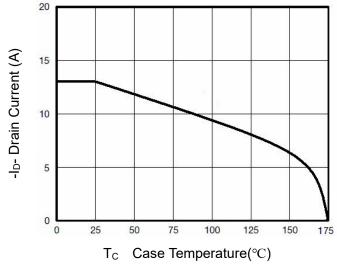


Figure 7 Capacitance vs Vds



**Figure 9 Drain Current vs Case Temperature** 

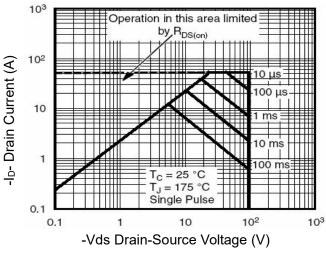


Figure 8 Safe Operation Area

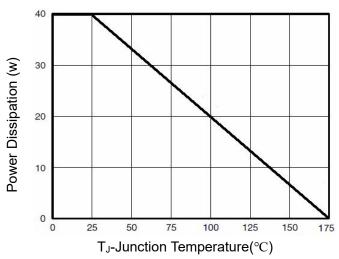
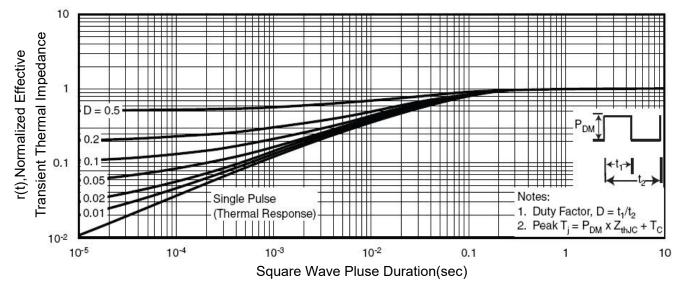


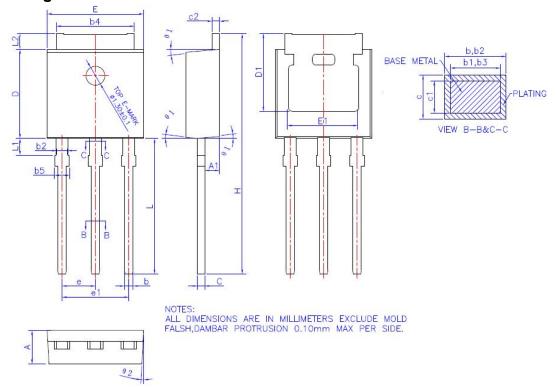
Figure 10 Power De-rating



**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-251 Package Information**



# COMMON DIMENSIONS (UNITS OF MEASURE =MILLIMETER)

SYMBOL	MIN	NOM	MAX
Α	2.20	2.30	2.35
A1	0,90	1.01	1.10
b	0,56		0,69
b1	0.55	0.60	0.65
b2	0.77	1	0.90
b3	0.76	0.81	0.86
b4	5.23	5.33	5.43
b5	<del></del>	10.00	1.05
С	0,46		0.59
c1	0.45	0.51	0.55
c2	0.46	- 19 <u>4-11</u>	0.59
D	6.00	6.10	6.20
D1	5.20	9.0-1.00-1	
E	6.50	6.60	6.70
E1	4.60	4.83	5.00
e	2,24	2,29	2,34
e1	4.47	4.57	4.67
Н	16.18	16,48	16.78
L	9.00	9.30	9.60
L1	0.95	1,16	1.35
L2	0.90	1.08	1.25
91	3°	5°	7°
θ2	1°	3°	5°



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